

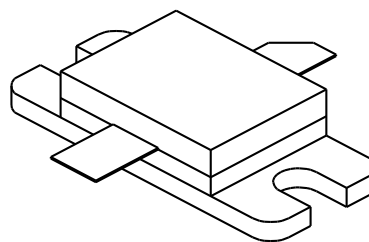
JTDA 150A

145 Watts, 36 Volts, Pulsed
Avionics 960 - 1215 MHz

GENERAL DESCRIPTION

The JTDA-150A is a high power COMMON BASE bipolar transistor. It is designed for pulsed systems in the frequency band 960-1215 MHz. The transistor includes input and output prematch for broadband performance. The device has gold thin-film metallization and diffused ballasting for proven highest MTTF. Low thermal resistance Solder Sealed Package reduces junction temperature, extends life.

CASE OUTLINE 55KT, STYLE 1



ABSOLUTE MAXIMUM RATINGS

Maximum Power Dissipation @ 25°C² 350 Watts

Maximum Voltage and Current

BVces Collector to Base Voltage 50 Volts
BVebo Emitter to Base Voltage 3.5 Volts
Ic Collector Current 15 Amps

Maximum Temperatures

Storage Temperature - 65 to + 200°C
Operating Junction Temperature + 200°C

ELECTRICAL CHARACTERISTICS @ 25 °C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Pout	Power Out	F = 960-1215 MHz	145			Watts
Pin	Power Input	Vcc = 36 Volts			24	Watts
Pg	Power Gain	PW = Note 1	8			dB
η_c	Collector Efficiency	DF = Note 1		45		%
VSWR	Load Mismatch Tolerance	F = 1215 MHz			3:1	

BVebo	Emitter to Base Breakdown	Ie = 20 mA	3.5			Volts
BVces	Collector to Emitter Breakdown	Ic = 60 mA	55			Volts
h_{FE}	DC - Current Gain	Ic = 5.0A, Vce = 5 V	20			
θ_{jc^2}	Thermal Resistance				0.5	°C/W

Note 1: JTIDS Pulse = 7 Micorseconds On / Off for 3.3 Millisec, 22 % Long term duty

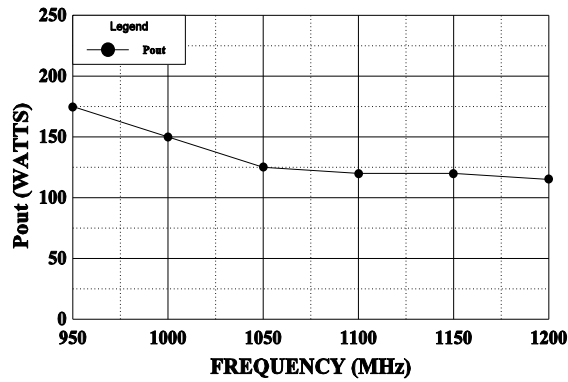
2: At rated pulse conditions

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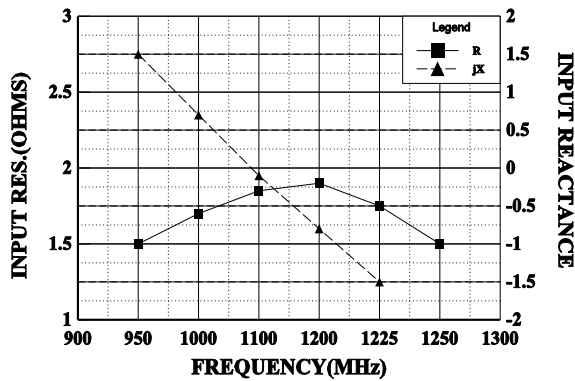
POWER OUTPUT vs FREQUENCY

Vcc = 36 V, Pin = 25 W



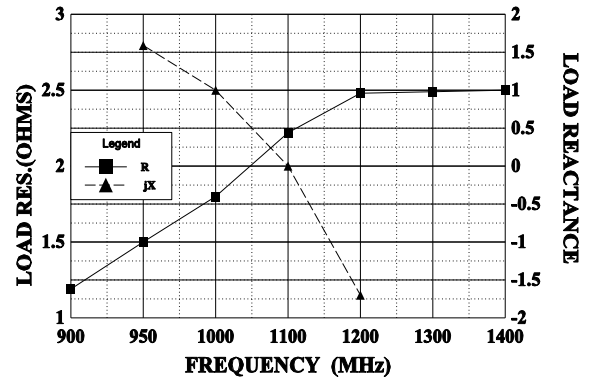
SERIES INPUT IMPEDANCE vs FREQUENCY

Vcc = 36 V, Po = 145 W



SERIES LOAD IMPEDANCE vs FREQUENCY

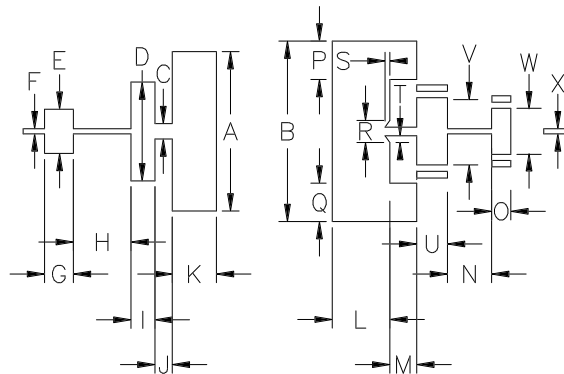
Vcc = 36 V, Po = 145 W



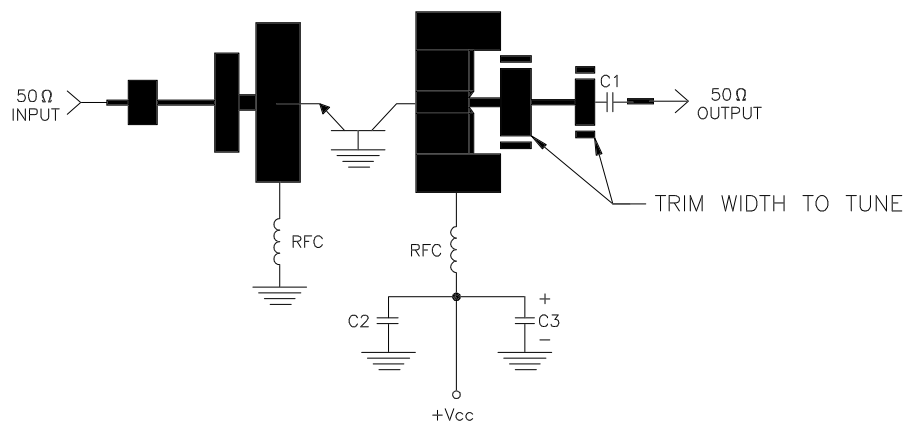
REVISIONS

ZONE	REV	DESCRIPTION	DATE	APPROVED
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DIM	INCHES
A	.830
B	.940
C	.080
D	.515
E	.230
F	.026
G	.150
H	.300
I	.125
J	.090
K	.230
L	.300
M	.140
N	.230
O	.100
P	.200
Q	.200
R	.115
S	.025
T	.035
U	.160
V	.350
W	.240
X	.026



JTDA 150A TEST CIRCUIT



DIELECTRIC = ROGERS 6010
 Er = 10.2, t = 25
 C1, C2 = 82pF CHIP ATC "A"
 C3 = 1000 MFD @ 50V
 RFC = 5 turns #22 wire 1/16" I.D.